

Features

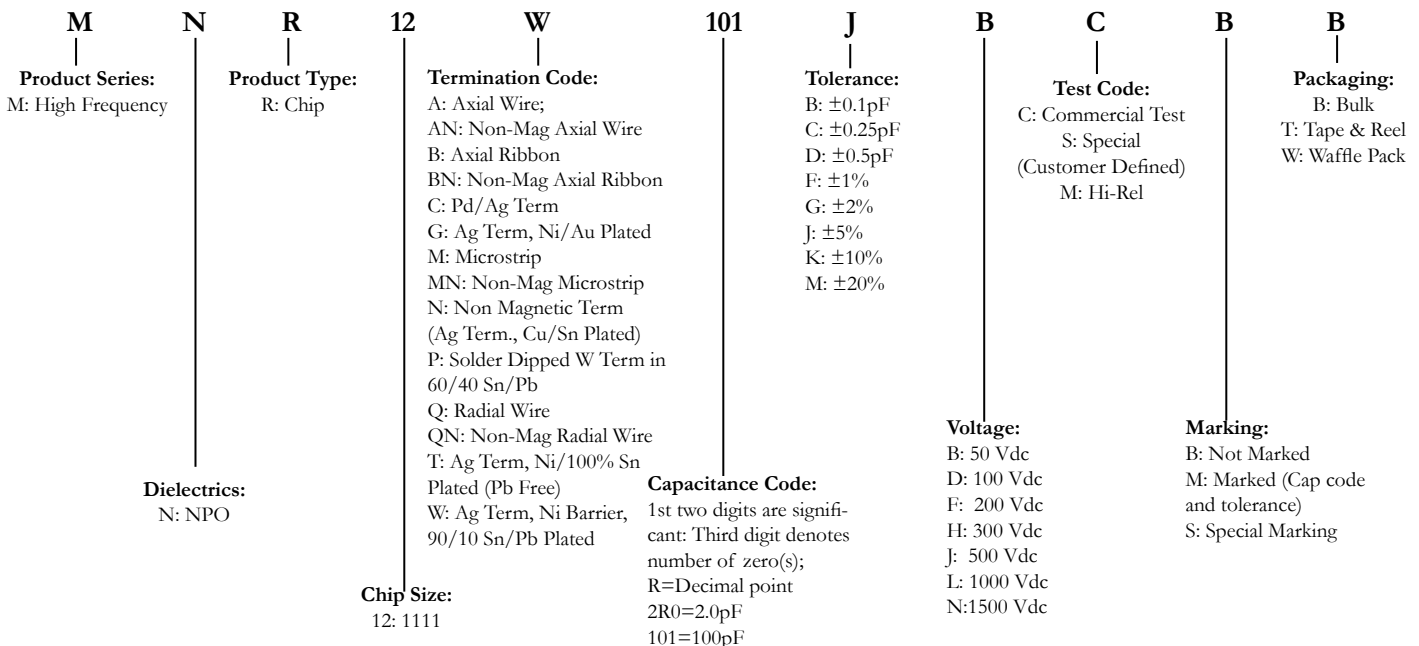
- Capacitance Range: 0.1pF to 5100pF
- High Q Low ESR/ESL
- High Power
- Ultra Stable Performance
- High Self-Resonance
- Operating Voltages
 - DC Voltage: 50V to 500V
- Extended WVDC up to 1500 Vdc
- Available with Encapsulation Option



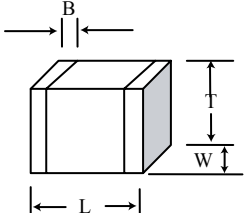
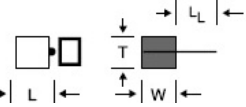
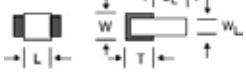
Applications

Typical Functional Applications: Bypass, Coupling, Tuning, Feedback, Impedance Matching and DC Blocking. Devices such as RF oscillators and precision timing circuits requiring a predictable temperature coefficient are examples of devices utilizing these capacitors.

AFM Part Number Code



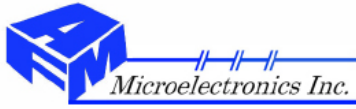
Chip Dimensions and Termination Options

AFM Series	Term Code	Type	MIL-PRF-55681	Outlines	Body Dimensions Inches (mm)			Lead and Termination Dimensions and Materials			
					Length(L)	Width(W)	Thickness(T)	B	Materials		
MNR12	W	Solder Plate	CDR14BP		.110 +.020-.010 (2.79 +0.51-0.25)		.102 (2.59) max	.015 (0.38) ±.010 (0.25) max	Solder Plated Over Nickel Barrier Termination 90 Sn/10 Pb		
	P	Pellet	CDR14BP						W Termination with Sn/Pb Solder Dip		
	T	Lead Free Solder Plated	N/A						Lead-Free and RoHS Compliant Tin Plated Over Nickel Barrier Termination		
	Q/ QN	Radial Wire/ Non-Magnetic	CDR23BP		.145±.020 (3.68±0.51)		.110±.015 (2.79±0.38)	.102 (2.59) max	Length(L ₁)	Width(W ₁)	Thickness(T ₁)
	R	Radial Ribbon	CDR24BP						.135±.015 (3.43±0.38)		
								.025 (6.35) min.	.093±.005 (2.36±0.13)	.004±.001 (0.102±0.25)	

Standard Capacitance Values

*STD.: Standard Voltage; EXT.: Extended Voltage

CAP CODE	CAP (pF)	TOL	RATED WVdc		CAP CODE	CAP (pF)	TOL	RATED WVdc		CAP CODE	CAP (pF)	TOL	RATED WVdc		CAP CODE	CAP (pF)	TOL	RATED WVdc	
			STD.*	EXT.*				STD.	EXT.				STD.	EXT.				STD.	EXT.
0R1	0.1	B	500	1500	3R3	3.3	B, C, D	500	1500	360	36	F, G, J, K, M	1500	1500	391	390	F, G, J, K, M	50	N/A
0R2	0.2	B			3R6	3.6				390	39				431	430			
0R3	0.3	B, C			3R9	3.9				430	43				471	470			
0R4	0.4	B, C			4R3	4.3				470	47				511	510			
0R5	0.5	B, C, D	4R7	4.7	510	51	F, G, J, K, M	500	1000	561	560	F, G, J, K, M	50	N/A					
0R6	0.6		5R1	5.1	560	56				621	620								
0R7	0.7		5R6	5.6	620	62				681	680								
0R8	0.8		6R2	6.2	680	68				751	750								
0R9	0.9	B, C, D	6R8	6.8	750	75	F, G, J, K, M	300	1000	821	820	F, G, J, K, M	50	N/A					
1R0	1.0		7R5	7.5	820	82				911	910								
1R1	1.1		8R2	8.2	910	91				102	1000								
1R2	1.2		9R1	9.1	101	100				112	1100								
1R3	1.3	B, C, D	100	10	111	110	F, G, J, K, M	300	1000	122	1200	F, G, J, K, M	50	N/A					
1R4	1.4		110	11	121	120				152	1500								
1R5	1.5		120	12	131	130				182	1800								
1R6	1.6		130	13	151	150				222	2200								
1R7	1.7	B, C, D	150	15	161	160	F, G, J, K, M	200	N/A	272	2700	F, G, J, K, M	50	N/A					
1R8	1.8		160	16	181	180				302	3000								
1R9	1.9		180	18	201	200				332	3300								
2R0	2.0		200	20	221	220				392	3900								
2R1	2.1	B, C, D	220	22	241	240	F, G, J, K, M	200	N/A	472	4700	F, G, J, K, M	50	N/A					
2R2	2.2		240	24	271	270				512	5100								
2R4	2.4		270	27	301	300													
2R7	2.7		300	30	331	330													
3R0	3.0		330	33	361	360													



MNR 12

RF/Microwave COG (NPO) Multilayer Capacitors

Specification and Performance

Piezoelectric and Aging Effect:	None
Temperature Range:	-55°C to +125°C
Temperature Coefficient of Capacitance:	0±30ppm/°C
Quality Factor (Q) :	>10,000 (1pF~200pF) at 1MHz >2000 (220pF~1000pF) at 1MHz >2000 (1100pF~5100pF) at 1KHz
Insulation Resistance (IR, at Rated Voltage):	0.1pF~470pF: 10 ⁶ MΩ min. at +25°C at rated WVDC 10 ⁵ MΩ min. at +125°C at rated WVDC 510pF~5100pF: 10 ⁵ MΩ min. at +25°C at rated WVDC 10 ⁴ MΩ min. at +125°C at rated WVDC
Dielectric Withstand Voltage (DWV):	250% of rated WVDC for 5 secs
Capacitance Drift:	±0.02% or ±0.02pF, whichever is greater

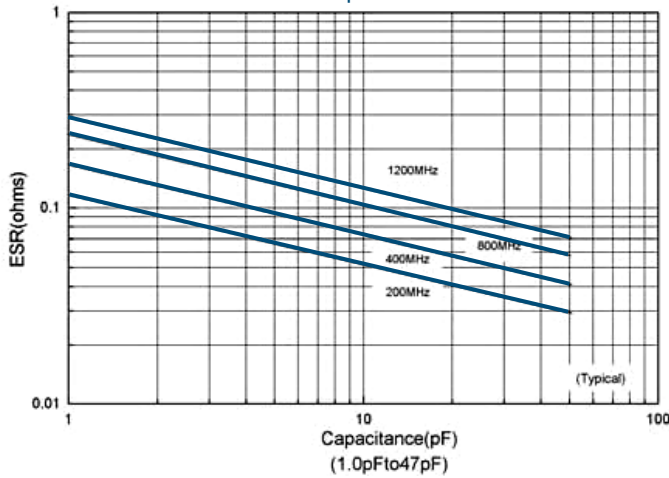
Environmental Tests

MNR12 Series Capacitors are designed and manufactured to meet and exceed the requirements of EIA-198, MIL-PRF-55681 and MIL-PRF-123.

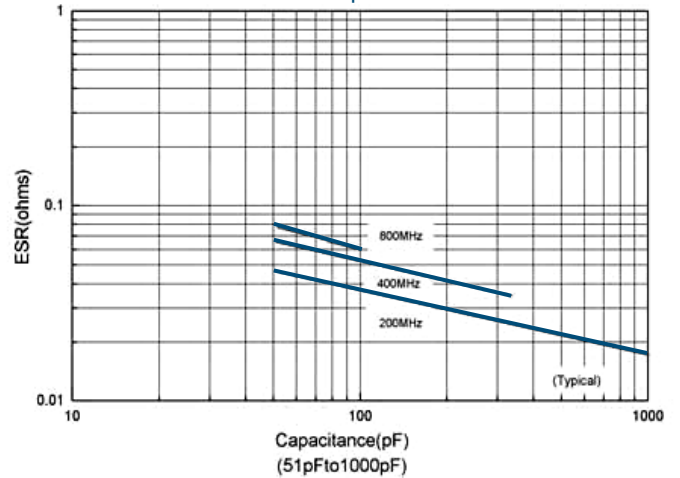
Item	Specifications	Method
Thermal Shock	DWV: the initial value IR: shall be not less than 30% the initial value Capacitance Change: no more than 0.5% or 0.5pF	MIL-STD-202, Method 107, Condition A. At the maximum rated temperature (-55°C and +125°C) stay 30 minutes, the time of removing shall be not more than 3 minutes. Perform the five cycles.
Moisture Resistance		MIL-STD-202, Method 106
Humidity (steady state)	DWV: the initial value IR: the initial value Capacitance Change: no more than 0.3% or 0.3pF	MIL-STD-202, Method 103, Condition A, with 1.5 volts D.C. applied while subjected to an environment of 85°C with 85% relative humidity for 240 hours min.
Life	IR: shall be not less than 30% the initial value Capacitance Change: no more than 0.2%	MIL-STD-202, Method 108, for 2000 hours, at 125°C. Rated voltage ≤500V: 200% Rated Voltage D.C. applied. 500V ≤ Rated Voltage ≤1250V: 120% Rated Voltage D.C. applied. Rated voltage >1250V: 100% Rated Voltage D.C. applied.

Performance Curve

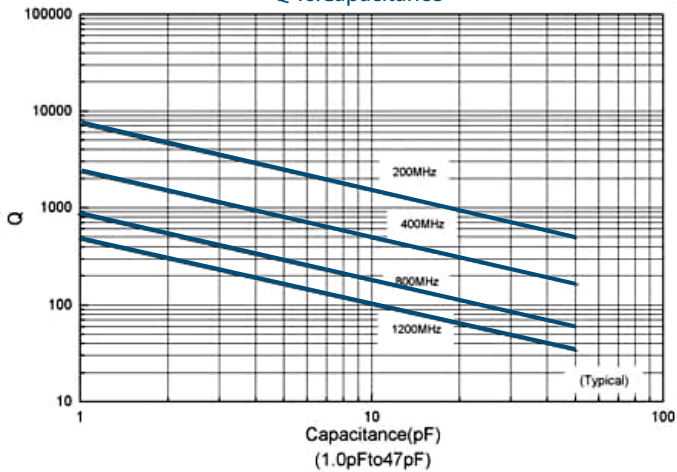
ESR vs.Capacitance



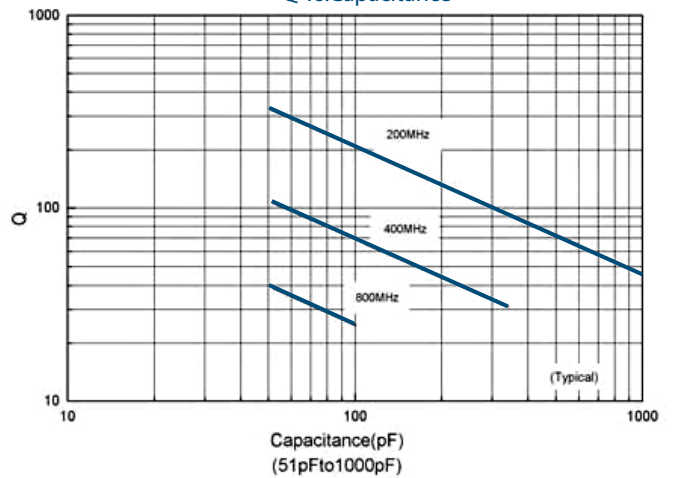
ESR vs.Capacitance



Q vs.Capacitance



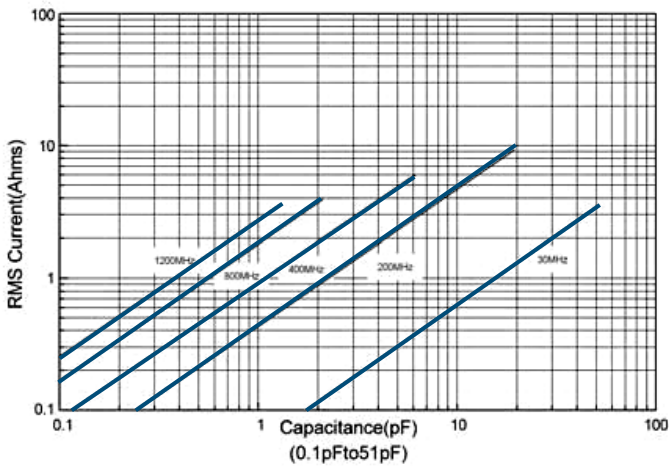
Q vs.Capacitance



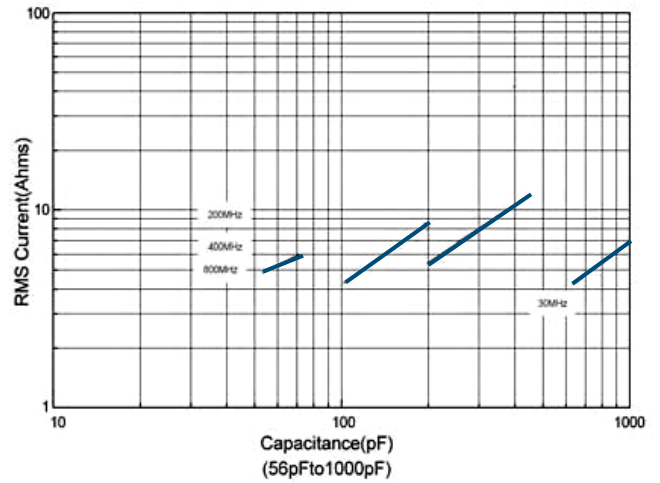
MNR 12

RF/Microwave COG (NPO) Multilayer Capacitors

Current Rating vs.Capacitance



Current Rating vs.Capacitance



Resonance vs.Capacitance

